NSN 5961-00-632-8268

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-632-8268 **Inclosure Material:** Metal **Overall Length:** Between 0.180 inches and 0.200 inches Overall Diameter: Between 0.115 inches and 0.125 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.7 threshold voltage **Voltage Tolerance In Percent:** -0.3/+0.3**Power Rating Per Characteristic:** 100.0 milliwatts large-signal output power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 71.0 degrees celsius ambient air **Test Data Document:** 82577-925522 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli